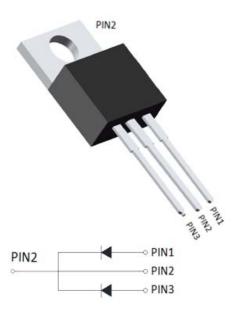




# **Schottky Diodes**



#### **Features**

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

#### **Typical Applications**

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

#### **Mechanical Data**

• Package: TO-220AB

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per

J-STD-002 and JESD22-B102

• Polarity: As marked

#### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR3045CT
Device marking code			MBR3045CT
Repetitive Peak Reverse Voltage	$V_{RRM}$	V	45
Average Rectified Output Current @60Hz sine wave, R-load, Ta=25°C	Io	А	30
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25℃	I <sub>FSM</sub>	А	250
Current Squared Time @1ms≤t≤8.3ms Tj=25℃,	l <sup>2</sup> t	A <sup>2</sup> s	260
Storage Temperature	T <sub>stg</sub>	°C	-55 ~ +150
Junction Temperature	Tj	°C	-55 ~ <b>+</b> 150

## **■Electrical Characteristics** (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR3045CT
Maximum instantaneous forward voltage drop per diode	$V_{FM}$	<b>V</b>	I <sub>FM</sub> =15.0A	0.6
Maximum DC reverse current at ated DC blocking voltage per diode	I <sub>RRM1</sub>	mA	V <sub>RM</sub> =V <sub>RRM</sub> Ta=25°C	0.2
	I <sub>RRM2</sub>		V <sub>RM</sub> =V <sub>RRM</sub> Ta=125℃	100

Note1:Pulse test:300uS pulse widh,1% duty cycle

Note2:Pulse test:pulse widh 40mS

### **MBR3045CT**

# **Thermal Characteristics** $(T_a$ =25 $^{\circ}$ C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBR3045CT
Thermal Resistance	Between junction and case	$R_{ heta J-C}$	°C/W	2.0

### **■Ordering Information** (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR3045CT	Approximate 1.9	50	2000	8000	Tube

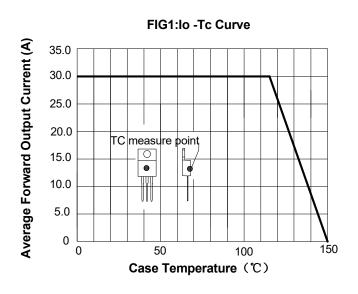
Peak Forward Surge Current (A)

0

2

5

### **■Characteristics** (Typical)



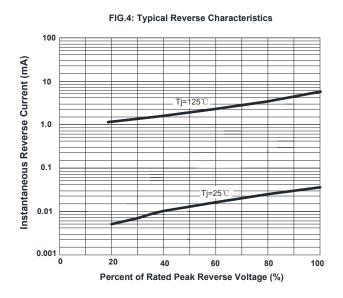
300
250
200
8.3ms Single
Half Sine-Wave
JEDEC Method
100
50

10

**Number of Cycles** 

FIG2:Surge Forward Current Capability

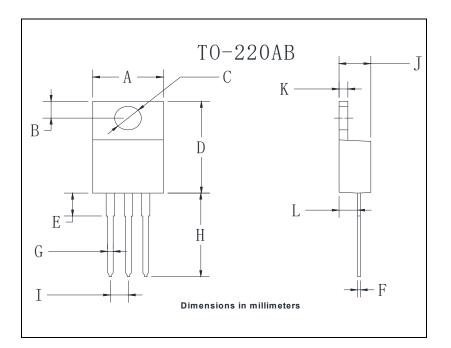
FIG3: Forward Voltage 100 50 Instantaneous Forward Current (A) 5.0 2.0 1.0 0.5 0.2 Ta=25℃ 0.3 1.0 0.4 0.5 0.6 0.7 8.0 0.9 Instantaneous Forward Voltage (V)



100



#### **■**Outline Dimensions



TO-220AB				
Dim	Min	Max		
Α	9.95	10.35		
В	2.55	2.95		
С	3.8	4.0		
D	14.95	15.25		
E	3.75	4.25		
F	0.26	0.5		
G	0.68	0.94		
Н	13.4	13.9		
1	2.35	2.65		
J	4.38	4.78		
K	1.14	1.4		
L	2.37	2.79		

#### **Disclaimer**

The information presented in this document is for reference only. Yangzhou Yangjie Electronic Technology Co., Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website http://www.21yangjie.com, or consult your nearest Yangjie's sales office for further assistance.